Diode Semiconductor Device - Page 1 of 1



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| Inclosure Material:                                  |  |
|--|--|
| Glass  |  |
| Overall Length:                                      |  |
| 0.560 inches   |  |
| Overall Diameter:                                    |  |
| 1.656 inches   |  |
| Function For Which Designed:                         |  |
| Rectifier  |  |
| Mounting Method:                                     |  |
| Press fit  |  |
| Features Provided:                                   |  |
| Hermetically sealed case                             |  |
| Semiconductor Material:                              |  |
| Silicon  |  |
| Voltage Rating In Volts Per Characteristic:          |  |
| 100.0 repetitive peak reverse voltage                |  |
| Current Rating Per Characteristic:                   |  |
| 400.00 amperes forward current, average absolute     |  |
| Maximum Operating Tempurature Per Measurement Point: |  |
| 200.0 degrees celsius junction                       |  |
| Terminal Type And Quantity:                          |  |
| 2 uninsulated wire lead                              |  |
| Shelf Life:  |  |
| N/a  |  |
| Unit Of Measure:                                     |  |
|  |  |
| Demilitarization:                                    |  |
| No   |  |
| Fiig:  |  |
| A110a0   |  |
|  |  |